

International Journal of Engineering Research in Electrical and Electronic Engineering (IJEREEE) Vol 2, Issue 8, August 2016

# A High Efficient Fully Soft Switched Isolated DC-DC Boost Converter

 <sup>[1]</sup>Aravind Murali, <sup>[2]</sup>Mr.Benny.K.K, <sup>[3]</sup>Mrs.Priya.S.P
<sup>[1]</sup> PG Scholar, <sup>[2]</sup> Associate Professor, <sup>[3]</sup> Assistant Professor Mangalam College of Engineering, Ettumanoor, Kerala

*Abstract:* This paper proposes a fully soft switched isolated DC-DC boost converter, which consists of only one switch and this switch is turned-on at zero current switching and turned-off at zero voltage switching. All the diodes in this proposed converter is turned-off at zero current condition, regardless of voltage and load variations. This converter consists of a lossless snubber and an isolation transformer. Leakage inductance of this isolation transformer is used for zero voltage switching (ZVS). All these features make this particular boost converter high efficient and low cost. Simulation results are given in order to validate the proposed concept and these results are compared with simulation results of conventional converters

Index Terms- Isolated step-up DC-DC converter, single switch, lossless snubber, fully soft switched.

### I. INTRODUCTION

The scarcity of conventional energy sources has become one of the most discussed global problems. Therefore we are looking for renewable energy sources such as Sun, wind, tides etc, instead of conventional energy sources. As the terminal voltage of such renewable energy sources are very low, a DC-DC converter is essential for the useful utilization of electrical energy. The existing methods of DCDC converter have its specific advantageous and disadvantageous based on its specifications and operating conditions [1], [4], [7]. The voltage conversion ratio range, maximal output power, number of components, power densities are the examples of such specifications. Many conventional DC-DC converters are available, but isolated DC-DC converters are commonly used to get the requirement of isolation standards. The electrical isolation in switching DC power supplies are provided by high frequency transformers [3]. The voltage stress on transformer windings and rectifier diodes are very high in conventional isolated DC-DC converters such as fly back converters, push-pull converters and full bridge converters etc. This will increase the components ratings and cost of the converter. Snubber circuits are used to reduce the voltage stress across the switch, but it reduces the efficiency of converter by dissipating some amount of power [1]-[4].

In step-up applications current fed isolated converters are more common due to its lower transformer turn ratio, lower diode rating and reduced ripples at input. There are two types of current- fed isolated converters; those are passive clamped current-fed converter and active clamped current fed converter [3], [5]. Structure and design of passive clamped current-fed converter is simple, but it suffers excessive power loss due to RCD snubber circuit and hard switching. In active clamped current-fed converter the voltage spikes due to leakage inductance of isolation transformer is clamped without any loss and also the main switch of this converter is turned-on in Zero Voltage Switching (ZVS). However these converters are not suited for low power applications, because they require at least four switches and its gate driver circuits that increase the cost and reduce the efficiency of converter [8]-[11]. Isolated converters with reduced number of switches have been developed for low power applications. Isolated converter with single switch can be turned-on in ZVS, but the switch is turned-off with hard switching. In Z-source converters a coupled inductor is used to increase the step-up ratio, but here switches are turned-on and turned-off with hard switching [6]. In PWM resonant single switch converter the voltage stress across the output diodes and leakage current are less than that of fly back converter, but the PWM single switch isolated resonant converter require a transformer with high turn ratio for step-up applications[3], [4], [12].

The proposed isolated DC-DC boost converter consist only one switch and this switch is turned-on in Zero Current Switching (ZCS) and turned-off in Zero Voltage Switching (ZVS). All the diodes used in this converter are turned-off in

Zero Current Switching and this reduce the voltage surge across the diodes due to diode reverse recovery. These



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fully soft switched conditions make a considerable reduction in switching losses in proposed converter from that of conventional isolated converters. A low rated lossless snubber is used here in order to makes the proposed converter high efficient and low cost.



Fig.1. Proposed Circuit Configuration

#### **II. PROPOSED CONVERTER**

the circuit configuration of Fig.1 shows proposed converter. The circuit consists of a input filter inductor Li, input DC source Vi, the main MOSFET switch S1, a clamp capacitor Cc and a lossless snubber circuit at the primary side of isolation transformer T1. Capacitor Cs, inductor Ls, diodes Ds1 and Ds2 are the components of snubber circuit. Lr-Cr is the series resonant circuit. D1 and D2 are the output diodes and C0 is the output diodes. The lossless snubber clamp the voltage spikes of the switch due to leakage inductance and turn-off the switch in ZVS. Zero current turn-off of diodes are achieved by Lr-Cr resonant circuit. Three resonance operations according to the variation of resonance frequency fr1 are shown in Fig. 2. Which are above resonance operation ( $DT_s < 0.5T_{r1}$ ), below resonance operation ( $DT_s > 0.5T_{r1}$ ), and resonance operation ( $DT_s = 0.5T_{r1}$ ), where resonance frequency can be expressed as in (1).

$$f_{r1} = \frac{1}{T_{r1}} = \frac{1}{2\pi\sqrt{L_r C_r}}$$
(1)

From Fig. 2, it is clear that the switch turn-off current and rate of change of current of diode (di/dt) in below resonance operation are less than that of above resonance operation, so that the total switching losses are smaller for below resonance operation. Therefore the proposed converter is operated under below resonance condition.





#### A. Operating Principles

Set

Key waveform of proposed converter during below resonance operation is shown in Fig. 3. It is assumed that the input filter and magnetizing inductances are constant current source during the switching period that means these inductances are large values. It is also assumed that clamp and output capacitances are constant voltage sources during switching period. These assumptions make the analysis of circuit simple. In this circuit voltage across the clamp capacitor Vcc same as that of input voltage Vi. In below resonance operation each switching periods consists of nine modes of operations and these nine modes are shown in fig 4.



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Modes of operations



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#### Fig. 4. Operation Modes in Below Resonance Operation Mode 1 $(t_0 - t_1)$

This mode begins when switch S1 is turned ON, then the source current and snubber capacitor (Cs) current will flow through the switch S1. The resonating current of resonant inductor (Lr) will flow through the switch (S1) in opposite direction of source current, so at the moment of turn-on current through the switch will be zero and it will increases with the slop of  $iL_r$ , resulting in ZCS turn-on of switch S1. This mode ends when current  $iL_r$  reaches OA and then the diode D1 is turned Off under ZCS condition.

### *Mode* 2 $(t_1 - t_2)$

In this mode  $V_{CC}$  will come across the primary winding of the isolation transformer, then the diode D2 will be turnedon and the direction of current through the resonant inductor (Lr) will change. At the same time the snubber capacitor (Cs) will discharge completely, and then the snubber inductor Ls will reverse its polarity and capacitor (Cs) charges in the negative direction. When the voltage across the capacitor Cs reaches V<sub>CC</sub>, then this mode will end.

#### *Mode 3* (t2 – t3 )

In this mode diode  $D_{s2}$  become forward biased condition and turned-On, then the remaining energy stored in the inductor  $L_s$  will dissipate through  $D_{s1}$ ,  $D_{s2}$  and  $C_c$ . Current through the diodes  $D_{s1}$  and  $D_{s2}$  become zero, when the inductor  $L_s$  dissipates completely. Then the snubber diodes turned-Off at zero current condition.

## *Mode 4* (t3 – t4 )

Duration of this mode is comparatively more than that of other modes, in this mode  $V_{CC}$  discharge completely and then  $iL_T$  reaches its negative peak. Now The  $L_T$  dissipates stored energy till current  $iL_T$  reaches 0 A and then the diode D2 is turned OFF under ZCS condition.

#### *Mode* 5 (t4 – t5 )

In this mode, sum of the input current Ii and the magnetizing current  $I_{Lm} f_{10W}$  through the switch S1. Secondary of the isolation transformer opens at this mode, because D1 and D2 are turned-off at this mode. Whatever may be the conditions at the end of mode-4 are continuing at this mode.

#### Mode 6 (t5 - t6)

This mode begins when  $S_1$  is turned OFF. Now, the current through the switch in mode-5 is flowing through the

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snubber capacitor (C<sub>S</sub>), Now the snubber capacitor(C<sub>S</sub>) is charging from -Vcc to zero and then a positive value equal to  $(V_0 - V_{crmax}) / n$ . When the capacitor C<sub>S</sub> voltage equals to this particular positive value, then this mode ends.

#### *Mode* 7 $(t_6 - t_7)$

When the VCs increases further the value (Vo - $V_{Crmax}$  /n, then the anode of D1 is more positive than that of cathode and then D1 turns on. The Lr and Cs start resonating and resonant current ILr follows through C<sub>s</sub>, D<sub>s2</sub>, L<sub>r</sub>, D<sub>1</sub> and C<sub>r</sub> and also this mode ends when the VCs becomes equal to maximum value. At this condition no more current will follow through the snubber diode  $D_{s2}$ , so Ds2 will turn-off at zero current condition.

#### *Mode* 8 (t7 - t8)

During this mode the snubber capacitor will discharge through the primary winding, up to which Vcs equal to (Vo- VCr;max) / n. After that capacitor will not discharge, then the snubber inductor  $L_S$  will reverse its polarity and dissipates energy stored in it through D<sub>s1</sub>, C<sub>s</sub>, primary winding and Vcc. After the complete dissipation of energy stored in Ls, current through the Ds2 will be zero and zero current turn-off of diode Ds2 is achieved at that moment.

#### Mode 9 (t8 - t9)

Switch S1 is in the turn-off state, and now the primary current of transformer is the sum of input current (Ii and magnetizing current (Ilm). This primary current is being transferred to secondary, now the current through the diode D1 is equal to  $(I_i + I_{Lm})/n$ . This mode ends when switch S1 is turned ON.

#### B. Design Procedure

In this section, components of the proposed converter are designed. A design example is given below with the following specifications: Output power V0=380V, input P0=250W, output voltage voltage Vi=38V and switching frequency fs=100kHz. In order to reduce the conduction loss of snubber components, the average value of snubber inductor current ILs,avg should be very small. This current ILs,avg is proportional to the snubber capacitance C<sub>s</sub>, but trying to reduce the snubber capacitance C<sub>S</sub> leads to increase the voltage rating of the switch. Therefore, considering a trade off between conduction losses of switch and snubber components, that is average value of snubber inductor current ILsavg is chosen to be 3% of average input current Ii,avg [1].

$$I_{Ls,avg} = 0.03I_{i,avg} = 0.27A$$
 (2)

The minimum value of duty ratio (Dmin), in order to keep the proposed converter in below resonance operation can be obtained from (3).

$$D_{min} = \pi f_s \sqrt{L_r C_r} \tag{3}$$

The resonant inductor (Lr) should be designed to reduce the reverse recovery effect of diode D1, in order to reduce reverse recovery effect of the diode, the resonant inductor should keep the duration of mode-1 (t1- t0) at least equal to 3 times that of reverse recovery time (trr). The duration of mode-1 can be expressed by following equation

$$t_1 - t_0 = 3t_{rr} = \frac{(l_i + l_{lm})L_r}{nV_0(1 + \frac{1}{2C_r}F_sR_s)}$$
(4)

By substituting the values  $I_i = 9A$ ,  $I_{lm} = 0.27A$ , n = 5, 0.5 in (3) and (4), and the resonant values  $L_r$  and  $C_r$ can be determined by 5µH and 560nF respectively. Value

of the snubber capacitance can be obtained from solving (5).

$$V_{Cs,max} = \frac{l_i - l_{Lm}}{n} \sqrt{\frac{L_r}{C_s}} + \frac{V_c - V_{cr,max}}{n}$$
(5)

V<sub>csmax</sub> is the maximum value of voltage that come across the snubber capacitor, so the equation for V<sub>csmax</sub> can be formed from the key waveform for the proposed converter, that is given in the Fig. 2.

$$V_{cs}(t_0) = 2\left(V_{cc} + \frac{V_0 - V_{cr,max}}{n}\right) - V_{Cs,max}$$
(6)



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Where  $V_{cc}$ , is the voltage across the coupling capacitor C<sub>c</sub>, which is equal to input voltage V<sub>i</sub> and V<sub>cr,max</sub> is given by (7)

$$V_{cr,max} = nV_{cc} + \frac{V_0}{2C_r f_s R_0} \tag{7}$$

 $V_{cs,max}$  and  $V_{cr,max}$  can be obtained from solving (6) and (7).

Substitution of these values in (5) determines the snubber capacitance ( $C_S$ ), which is equal to 16nF.

Snubber inductance  $L_s$  should be designed to minimize the reverse recovery effect of snubber diodes  $D_{s1}$  and  $D_{s2}$ . The reverse recovery effect can be reduced by keeping the time interval t2 to t3 greater than that of reverse recovery time ( $t_{TT}$ ) of snubber diodes. Duration of mode-3 (t3 - t2) can be obtained from the key wave form of proposed converter in Fig.2. Then, the duration of mode-3 is given by (8).

$$t_3 - t_2 = 3t_{rr2} = \frac{V_{Cs}(t_0)L_s\sin(\cos^{-1}-V_i/V_{cs}(t_0))}{V_i}\sqrt{\frac{C_s}{L_s}}$$
(8)

Where  $t_{TT1}$  is the reverse recovery time of snubber diode, which is taken as 10ns. The snubber inductance (L<sub>s</sub>)  $5\mu$ H

can be obtained from solving (8), which is equal to

#### TABLE 1 COMPONENT RATING

COMPONENTS	RATING
Filter inductor L <sub>i</sub>	100µ H
Snubber inductor L <sub>s</sub>	5µ H
Snubber capacitor C <sub>s</sub>	16nF
Clamp capacitor C <sub>c</sub>	82µ F
<i>Transformer</i> Leakage inductance Magnetizing inductance Turn ratio VA	5μ H 93μ H 1:5 273V A
Resonant capacitor Cr	560n F
Output capacitor C <sub>0</sub>	1μ H

## **III. SMULATION RESULT**

Simulation of the proposed converter is done in MATLAB with designed values of components as in Table-1. Fig. 5 and 6 show the output voltage and current of proposed converter. The duty ratio (D) of the main switch and switching frequency is taken as 0.62 and 100kHz respectively.



Fig. 5. Output Voltage of proposed converter in open loop simulation V0=409.4V, under Vi=38V, R0=577 $\Omega$ 



Fig. 6. Output current of proposed converter in open loop simulation  $I_0=0.7088A$ , under  $V_i=38V$ ,  $R_0=577\Omega$ 

Input voltage of proposed DC-DC converter  $(V_{in})$  is 38V and input current  $(I_{in})$  is 7.37A, so the input power (Pin) is 280.06W. Output voltage of proposed DC-DC converter (V<sub>0</sub>) is 391.21V and output current (I<sub>0</sub>) is 0.68A, so the output power (Po) is 266.02W. So the efficiency of the proposed DC-DC converter can be calculated from the following equation

$$efficiency = \frac{P_0}{P_{in}} \times 100 = \frac{290.18}{301.68} \times 100 = 96.18\%$$
(9)

# Fig. 9. shows the current and voltage of the main switch



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S1. Here the voltage across the switch  $(S_1)$  is zero at the moment of turn-off. The current through the switch  $(S_1)$  is zero at the moment of turn-on. So the switch is turned-on in zero current switching and turned-off in Zero voltage switching.



Fig. 7. Voltage and Current of Switch S1 with snubber circuit

Fig. 10. shows the current and voltage of the main switch S1 of the proposed DC-DC boost converter, without snubber circuit.



Fig. 8. Voltage and Current of Switch S1 Without snubber Circuit

Here the simulation results of proposed converter are compared with conventional converters such as Integrated Boost Resonant converter (IBR) [7], conventional flyback converter, and conventional DC-DC boost converter [13]. For these converters the simulation results are taken under input voltage Vi=38V, duty ratio D =0.62, output resistance R0=577\_, and switching frequency fs=100kHz. A comparison of output voltages of proposed converter and conventional converters are shown in Fig.9, and the values are tabulated in Table-2.



Fig. 9. Comparison of Output Voltage of Proposed Converter with Conventional Converters under  $V_i=38V$ ,  $R_0=577\Omega$ 





Fig. 10. Comparison of Output Current of Proposed Converter with Conventional Converters under Vi=38V, R0=577Ω

Table-3		
Comparison of Output Current		

Converters	Output Current I <sub>0</sub> (A)
Conventional DC-DC Boost Converter	0.1559
Conventional Flyback Converter	0.2944
IBR Converter	0.54
Proposed Converter	0.7088



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The values of input current of converters are tabulated in Table-4

Table-4Comparison of Input Current

Converters	Input Current I <sub>0</sub> (A)
Conventional DC-DC Boost Converter	0.453
Conventional Flyback Converter	1.598
IBR Converter	5.3
Proposed Converter	7.939

Efficiency of proposed converter is calculated in (9) which is equal to 96.16%. Efficiency of other converters also can be calculated using (9), which are tabulated in Table-5.

#### Table5 Comparison of Efficiencies

Converters	Efficiency (%)
Conventional DC-DC Boost Converter	90.30
Conventional Flyback Converter	91.34
IBR Converter	92.34
Proposed Converter	96.18

From Table-5 it is clear that the efficiency of proposed isolated DC-DC converter is higher than that of conventional converters. From Fig.9, it is also clear that the step-up ratio of proposed converter is very high. Proposed DC-DC converter provides an output voltage of 409.4V for an input voltage of 38V, but the output voltage of latest IBR converter is only 344.4V for the same input voltage under same conditions.

## **IV. CONCLUSION**

In this paper, a high efficient fully soft switched isolated DC-DC boost converter was proposed for step-up applications. This converter consists only one switch which is fully switched and the snubber circuit for this switch is lossless. All the diodes used in this converter are turned –off at zero voltage condition. The proposed converter has a high efficiency of 96.16 %, this is 4% greater than that of latest IBR converter. The proposed converter also has a high step-up ratio and a well stabilized output voltage.

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